

PMV35EPE 30 V, P-channel Trench MOSFET 6 July 2016

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-30	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-5.3	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I _D = -4.2 A; T _j = 25 °C		-	35	45	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G G S 017aaa259

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMV35EPE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

7. Marking

Table 4. Marking codes	
Type number	Marking code[1]
PMV35EPE	EK%

[1] % = placeholder for manufacturing site code

8. Limiting values

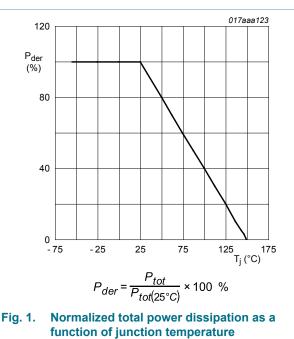
Table 5. Limiting values

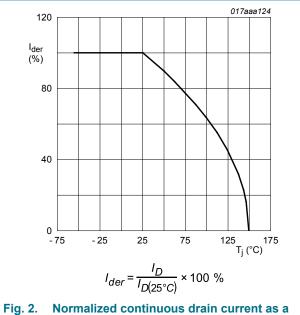
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-30	V
V _{GS}	gate-source voltage			-20	20	V
ID	drain current	V _{GS} = -10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-5.3	А
		V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	-4.2	А
		V _{GS} = -10 V; T _{amb} = 100 °C	[1]	-	-2.7	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-17	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	480	mW
			[1]	-	1.2	W
		T _{sp} = 25 °C		-	6.95	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode		·			
ls	source current	T _{amb} = 25 °C	[1]	-	-4	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



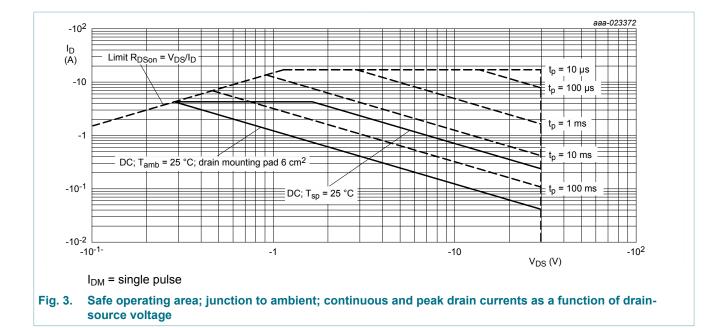


function of junction temperature

Product data sheet

PMV35EPE

30 V, P-channel Trench MOSFET



9. Thermal characteristics

Table 6. Thermal characteristics

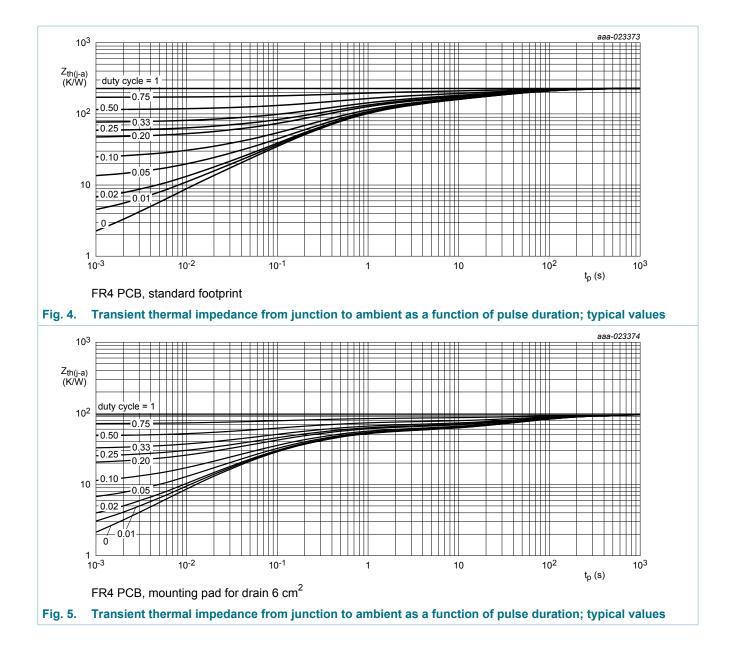
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	227	261	K/W
			[2]	-	91	104	K/W
		t ≤ 5 s	[2]	-	57	66	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	18	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

PMV35EPE

30 V, P-channel Trench MOSFET



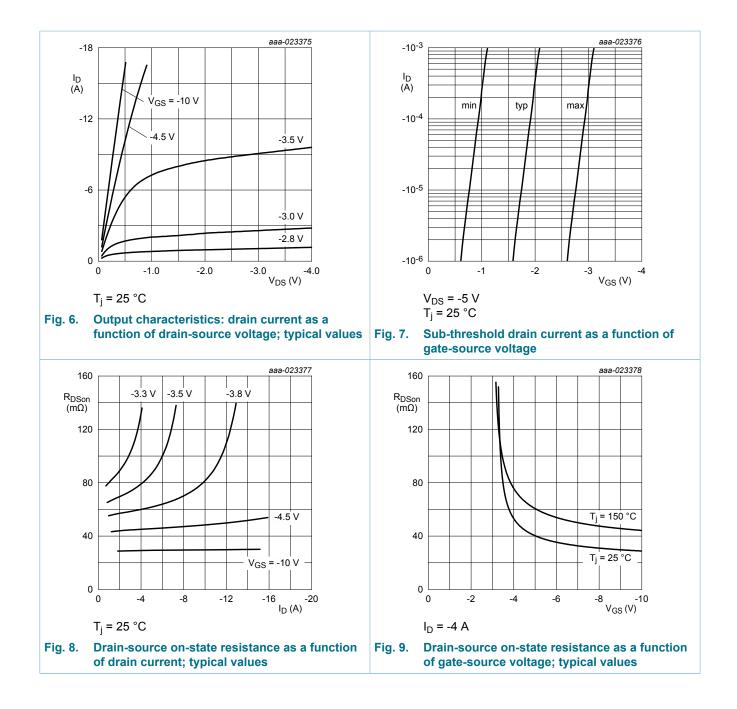
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	1				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -250 μA; V _{GS} = 0 V; T _j = 25 °C	-30	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-1	-2	-3	V
I _{DSS}	drain leakage current	V _{DS} = -30 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
	V	V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	2	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
R _{DSon}	drain-source on-state	V_{GS} = -10 V; I _D = -4.2 A; T _j = 25 °C	-	35	45	mΩ
resistance	resistance	V_{GS} = -10 V; I _D = -4.2 A; T _j = 150 °C	-	51	67	mΩ
		V_{GS} = -4.5 V; I _D = -3.3 A; T _j = 25 °C	-	49	72	mΩ
9fs	forward transconductance	V _{DS} = -10 V; I _D = -4.2 A; T _j = 25 °C	-	13.5	-	S
R _G	gate resistance	f = 1 MHz	-	13	-	Ω
Dynamic ch	naracteristics		· ·			_
Q _{G(tot)}	total gate charge	V_{DS} = -15 V; I _D = -4.2 A; V _{GS} = -10 V;	-	12.8	19.2	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.2	-	nC
Q _{GD}	gate-drain charge		-	2.2	-	nC
C _{iss}	input capacitance	V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V;	-	793	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	134	-	pF
C _{rss}	reverse transfer capacitance		-	84	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -15 V; I_{D} = -4.2 A; V_{GS} = -10 V;	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	19	-	ns
t _{d(off)}	turn-off delay time		-	36	-	ns
t _f	fall time		-	19	-	ns
Source-drai	in diode	·				
V _{SD}	source-drain voltage	I _S = -4 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.8	-1.2	V

PMV35EPE

30 V, P-channel Trench MOSFET

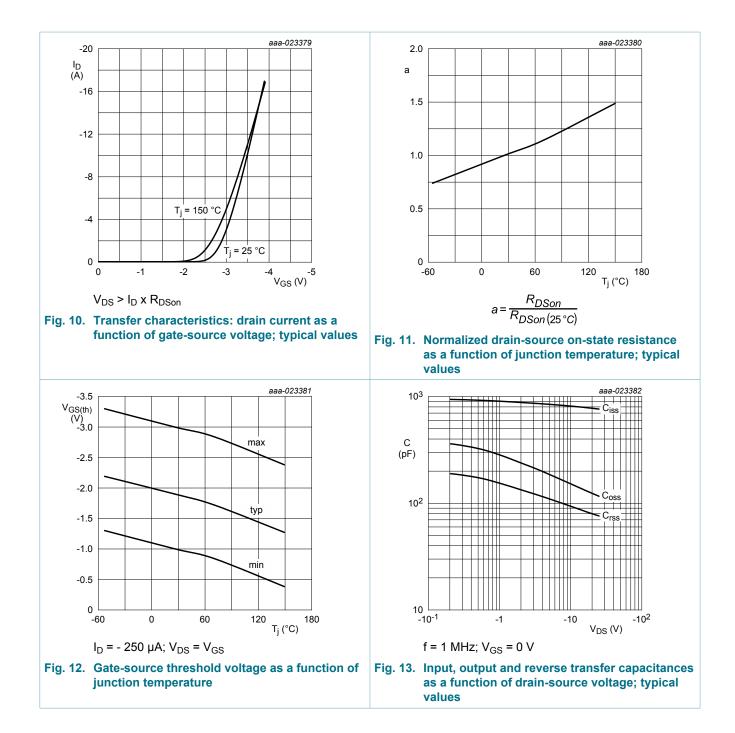


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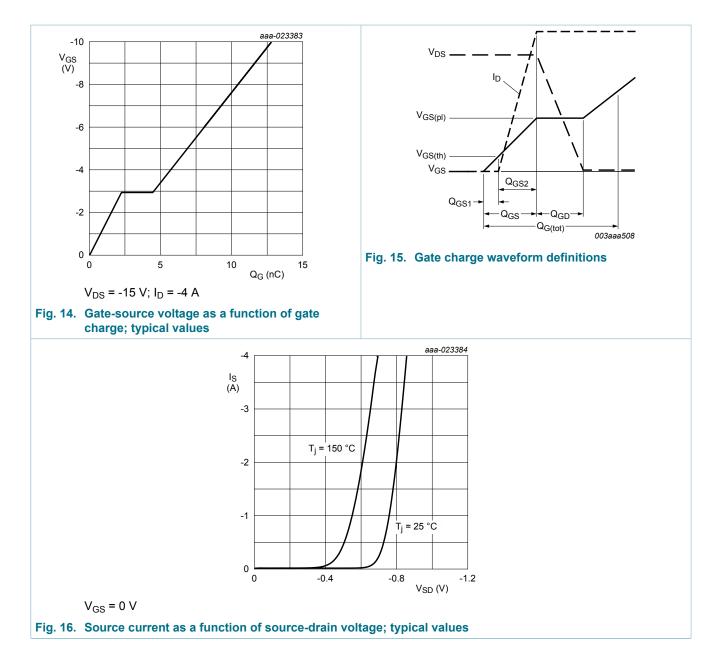
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30 V, P-channel Trench MOSFET

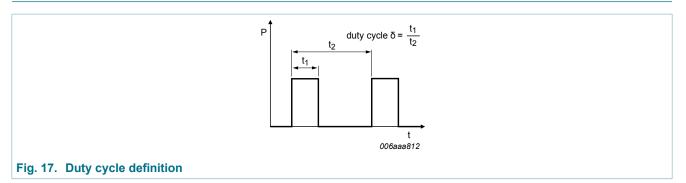


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30 V, P-channel Trench MOSFET

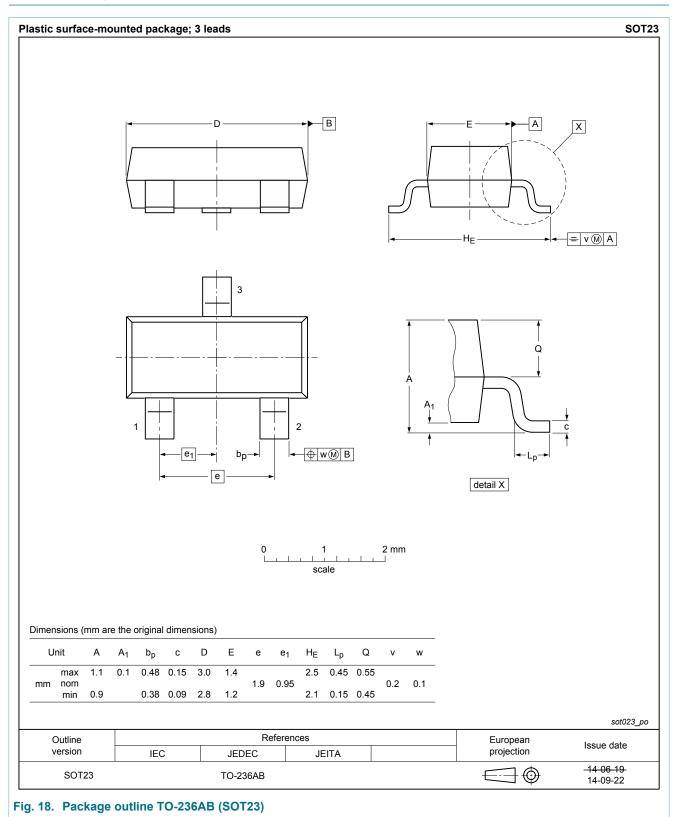


11. Test information



30 V, P-channel Trench MOSFET

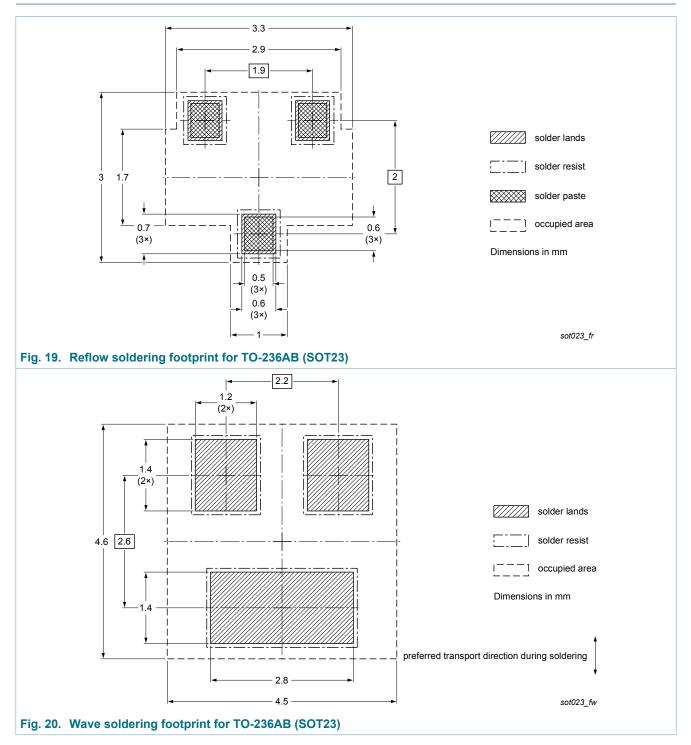
12. Package outline



PMV35EPE

30 V, P-channel Trench MOSFET

13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV35EPE v.1	20160706	Product data sheet	-	-		

30 V, P-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PMV35EPE

30 V, P-channel Trench MOSFET

16. Contents

1.	General description	.1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	.2
8.	Limiting values	. 3
9.	Thermal characteristics	. 4
10.	Characteristics	. 6
11.	. Test information	. 9
12.	Package outline	10
13.	Soldering	11
	Revision history	
15.	Legal information	13

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